

TVS Diode

Transient Voltage Suppressor Diodes

ESD207-B1-02 Series

Ultra Low Clamping Bi-directional ESD / Transient / Surge Protection Diodes

ESD207-B1-02ELS
ESD207-B1-02EL

Data Sheet

Revision 1.3, 2013-12-19
Final

Revision History: Revision 1.2, 2013-11-15

Page or Item	Subjects (major changes since previous revision)
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Revision 1.3, 2013-12-19

5	Table 2-2) updated

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Last Trademarks Update 2010-10-26

1 Ultra Low Clamping Bi-directional ESD / Transient / Surge Protection Diodes

1.1 Features

- ESD / transient / surge protection of one data / V_{bus} line exceeding standard:
 - IEC61000-4-2 (ESD): ± 30 kV (air / contact discharge)
 - IEC61000-4-4 (EFT): ± 50 A (5/50 ns)
 - IEC61000-4-5 (surge): ± 8 A (8/20 μ s)
- Bi-directional, symmetrical working voltage up to $V_{RWM} = \pm 3.3$ V
- Medium capacitance: $C_L = 14$ pF (typ.)
- Ultra low clamping voltage $V_{CL} = 7$ V (typ.) @ $I_{PP} = 16$ A (TLP)
- Ultra low dynamic resistance $R_{DYN} = 0.13 \Omega$ typ.
- Pb-free (RoHS compliant) and halogen free package



1.2 Application Examples

- Audio Line, Speaker, Headset, Microphone Protection
- Human Interface Devices (Keyboard, Touchpad, Buttons)

1.3 Product Description

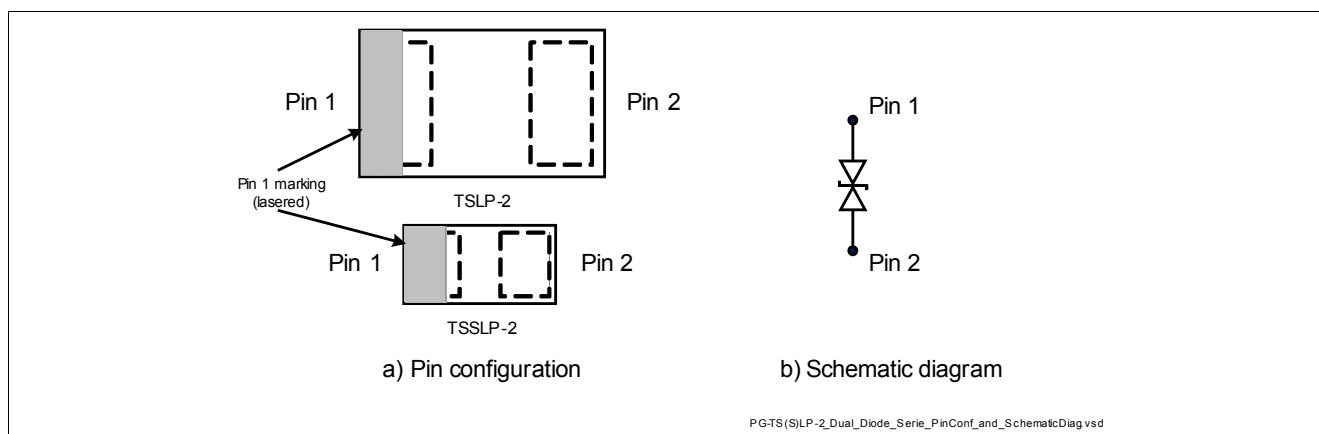


Figure 1-1 Pin Configuration and Schematic Diagram

Table 1-1 Ordering Information

Type	Package	Configuration	Marking code
ESD207-B1-02ELS	TSSLP-2-3	1 line, bi-directional	<u>Y</u>
ESD207-B1-02EL	TSLP-2-19	1 line, bi-directional	A

2 Characteristics

Table 2-1 Maximum Ratings at $T_A = 25\text{ °C}$, unless otherwise specified¹⁾

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
ESD contact discharge ²⁾	V_{ESD}	–	–	30	kV
Peak pulse current ($t_p = 8/20\text{ }\mu\text{s}$) ³⁾	I_{PP}	–	–	8	A
Peak pulse power ($t_p = 8/20\text{ }\mu\text{s}$) ³⁾	P_{PK}	–	–	65	W
Operating temperature range	T_{OP}	-40	–	125	°C
Storage temperature	T_{stg}	-65	–	150	°C

1) Device is electrically symmetrical

2) V_{ESD} according to IEC61000-4-2

3) I_{PP} according to IEC61000-4-5

Attention: Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

2.1 Electrical Characteristics at $T_A = 25\text{ °C}$, unless otherwise specified

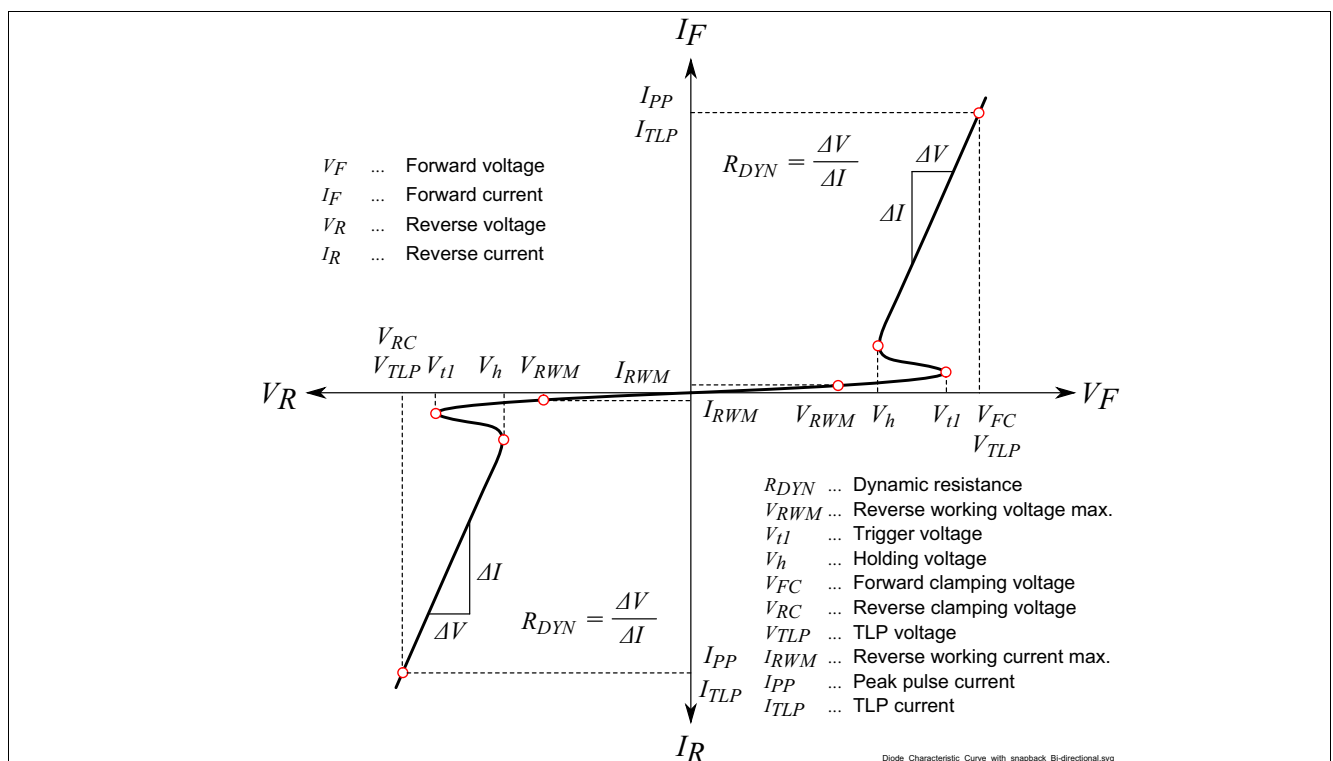


Figure 2-1 Definitions of electrical characteristics

Characteristics

Table 2-2 DC Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified¹⁾

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Reverse working voltage	V_{RWM}	–	–	3.3	V	
Reverse current	I_R	–	–	50	nA	$V_R = 3.3\text{ V}$
Trigger voltage	V_{t1}	3.65	–	–	V	
Holding voltage	V_h	3.65	4.4	–	V	$I_R = 10\text{ mA}$

1) Device is electrically symmetrical

Table 2-3 AC Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Line capacitance	C_L	–	14	20	pF	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$

Table 2-4 ESD and Surge Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clamping voltage ¹⁾ Pin 1 to GND	V _{CL}	—	7	—	V	I _{TLP} = 16 A
		—	9	—		I _{TLP} = 30 A
Clamping voltage ¹⁾ GND to Pin 1		—	7.5	—		I _{TLP} = 16 A
		—	9	—		I _{TLP} = 30 A
Clamping voltage ²⁾		—	4.5	5.8		I _{PP} = 1 A
		—	6.8	8.1		I _{PP} = 8 A
Dynamic resistance ¹⁾	R _{DYN}	—	0.13	—	Ω	

1) ANSI/ESD STM5.5.1 - Electrostatic Discharge Sensitive Testing using Transmission Line Pulse (TLP) Model. TLP conditions: $Z_0 = 50\text{ }\Omega$, $t_p = 100\text{ ns}$, $t_r = 0.6\text{ ns}$, I_{TLP} and V_{TLP} averaging window: $t_1 = 30\text{ ns}$ to $t_2 = 60\text{ ns}$, extraction of dynamic resistance using least squares fit of TLP characteristic between $I_{TLP1} = 5\text{ A}$ and $I_{TLP2} = 40\text{ A}$. Please refer to Application Note AN210 [\[1\]](#)

2) I_{PP} according to IEC61000-4-5 ($t_p = 8/20\text{ }\mu\text{s}$)

2.2 Typical Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

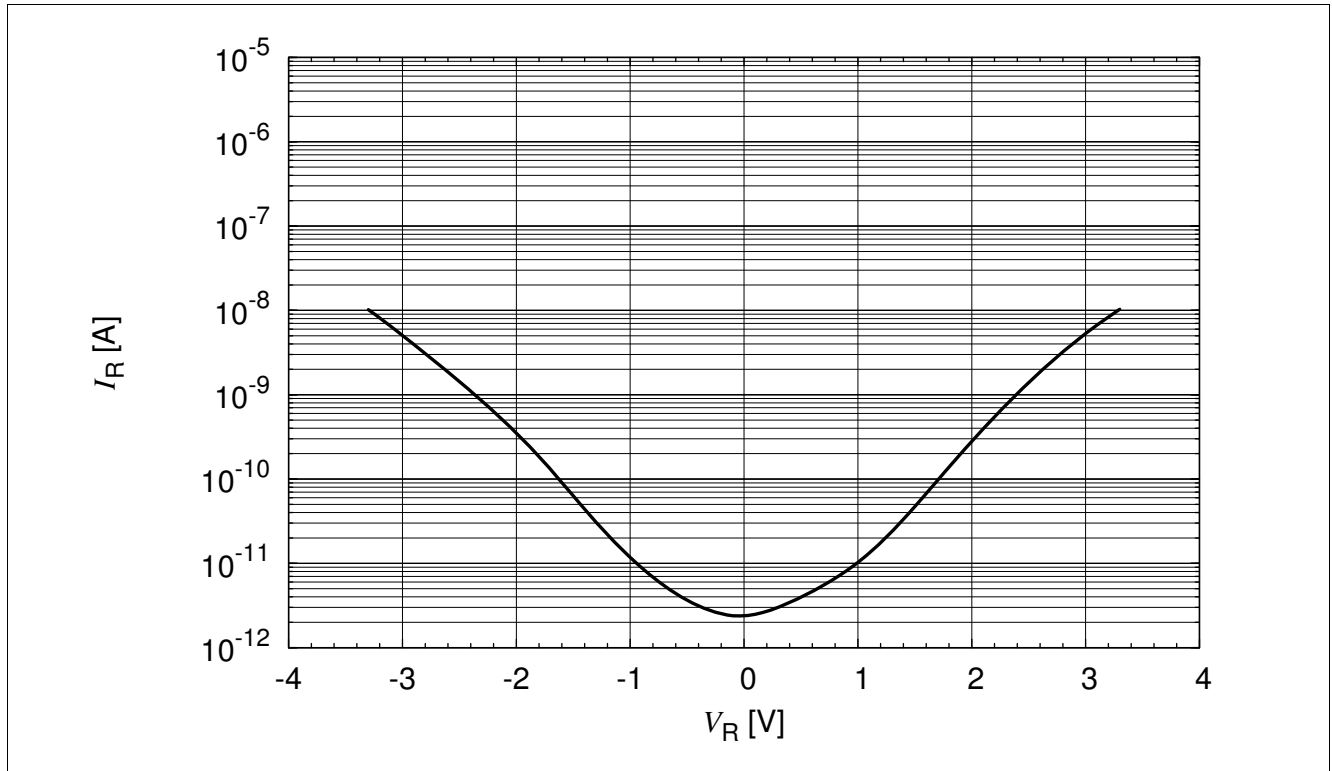


Figure 2-2 Reverse current: $I_R = f(V_R)$

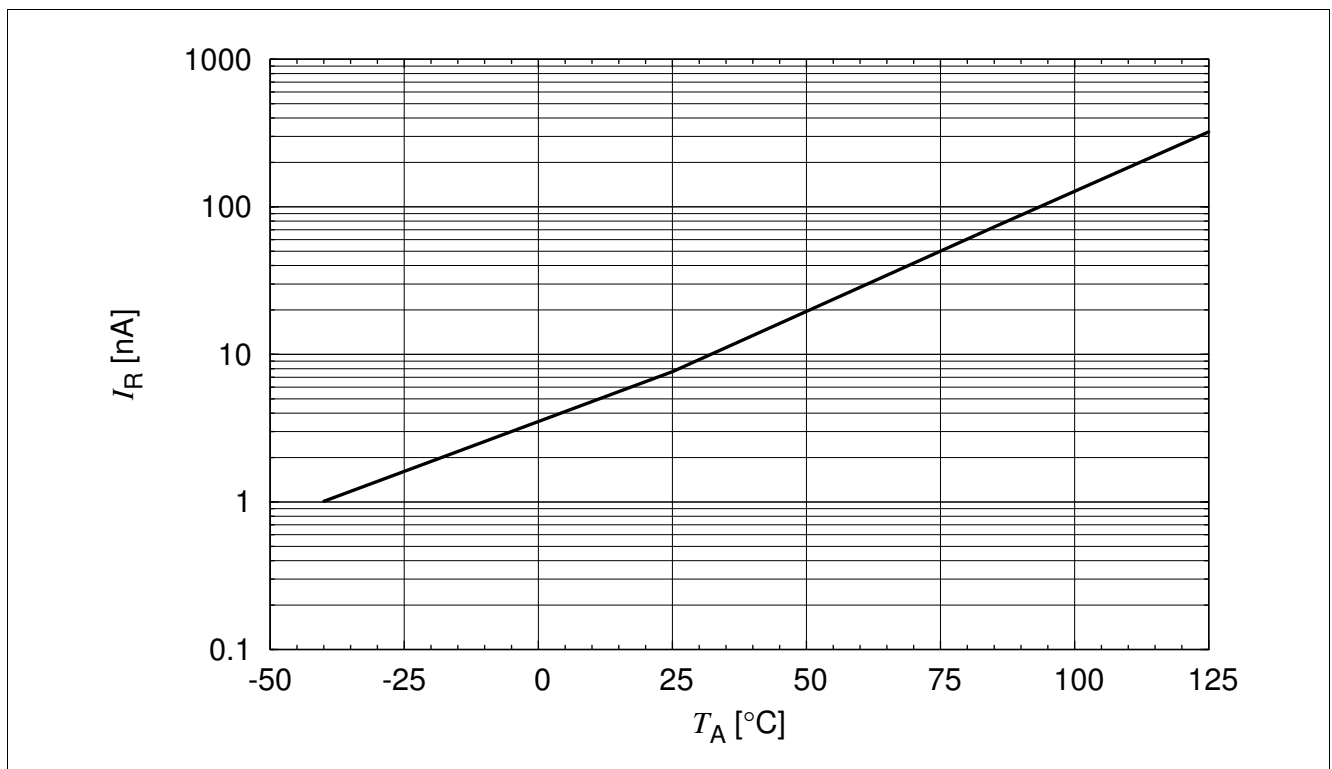


Figure 2-3 Reverse current: $I_R = f(T_A)$, $V_R = 3.3\text{ V}$

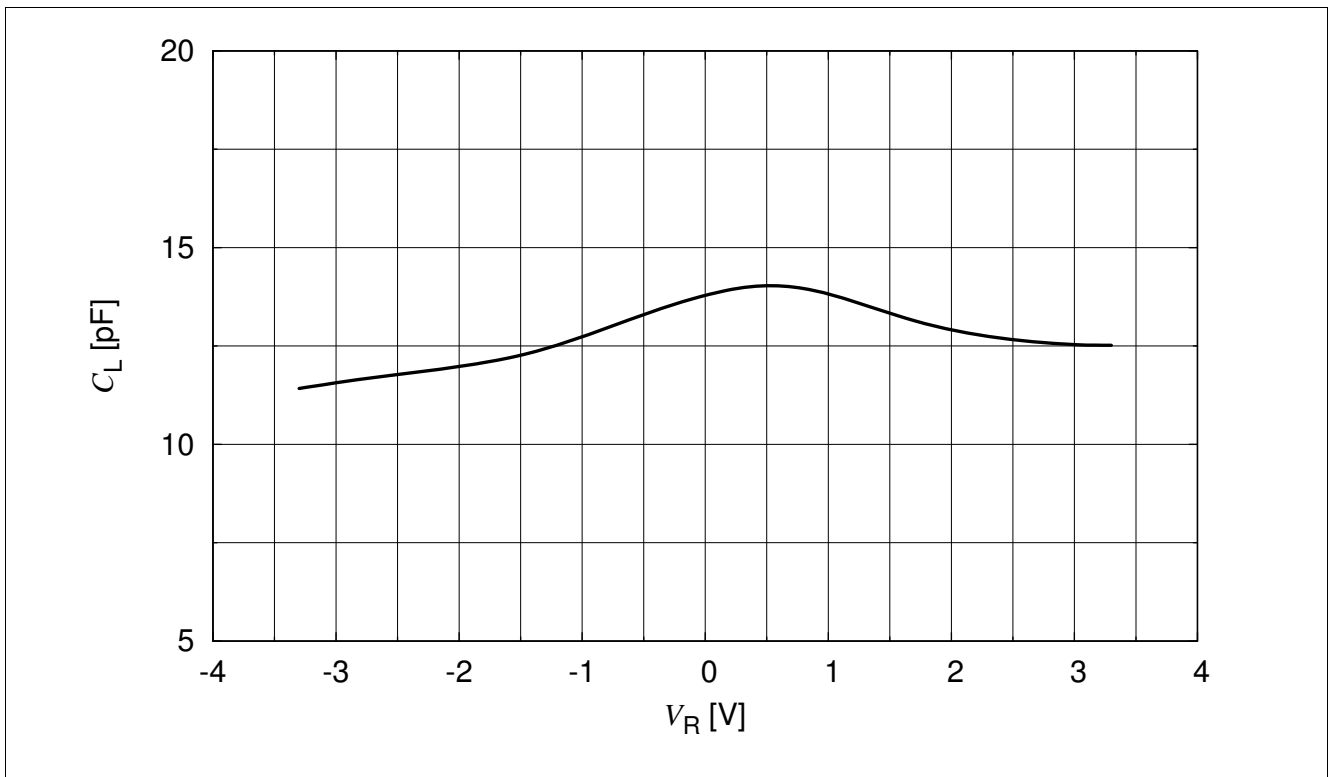


Figure 2-4 Line capacitance: $C_L = f(V_R)$, $f = 1\text{MHz}$

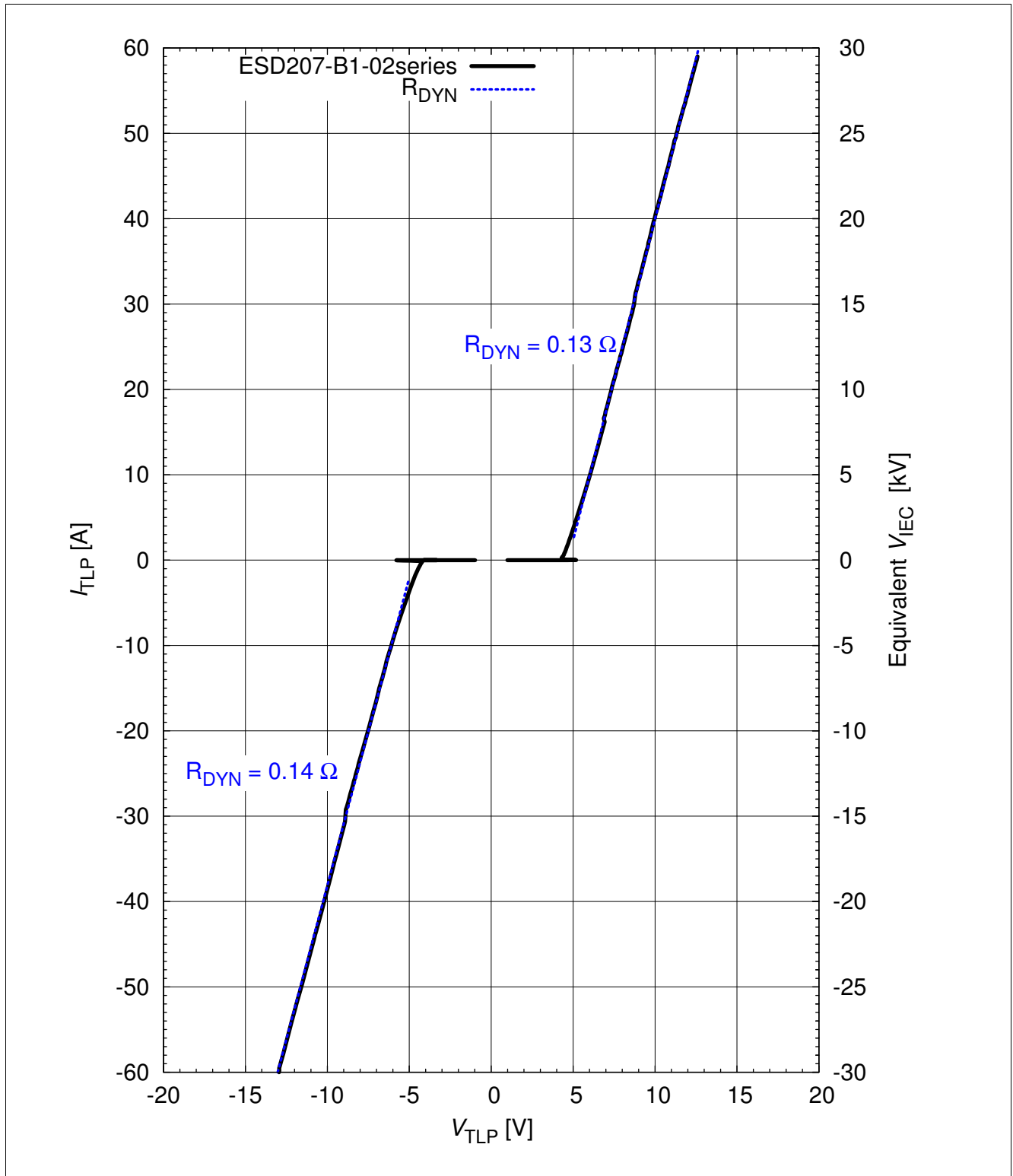


Figure 2-5 Clamping voltage (TLP): $I_{TLP} = f(V_{TLP})$ according ANSI/ESD STM5.5.1 - Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model. TLP conditions: $Z_0 = 50 \Omega$, $t_p = 100$ ns, $t_r = 0.6$ ns, I_{TLP} and V_{TLP} averaging window: $t_1 =$ ns to $t_2 = 60$ ns, extraction of dynamic resistance using squares fit to TLP characteristics between $I_{TLP1} = 5$ A and $I_{TLP2} = 40$ A. Please refer to Application Note AN210 [1]

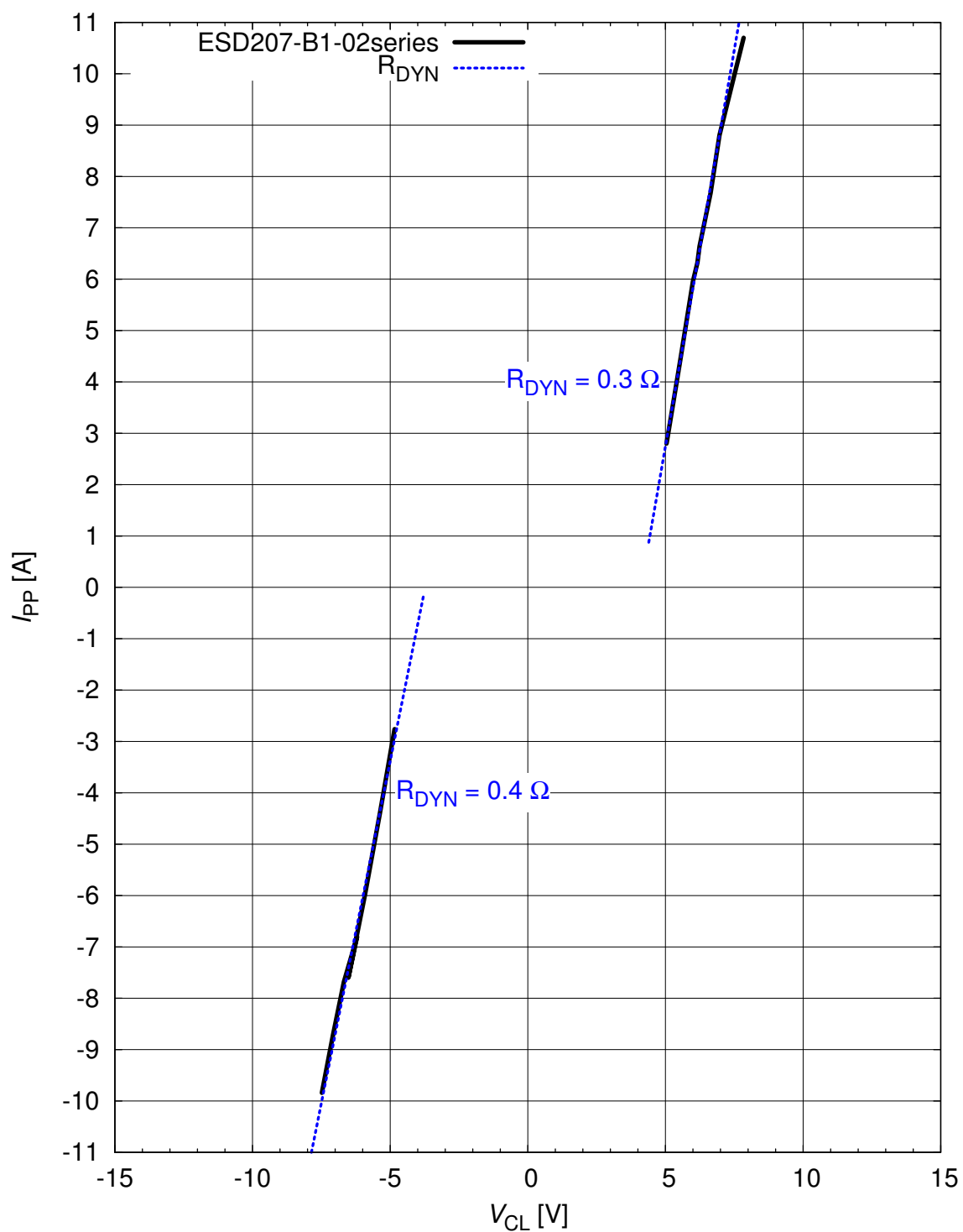


Figure 2-6 Pulse current (IEC61000-4-5) versus clamping voltage: $I_{PP} = f(V_{CL})$

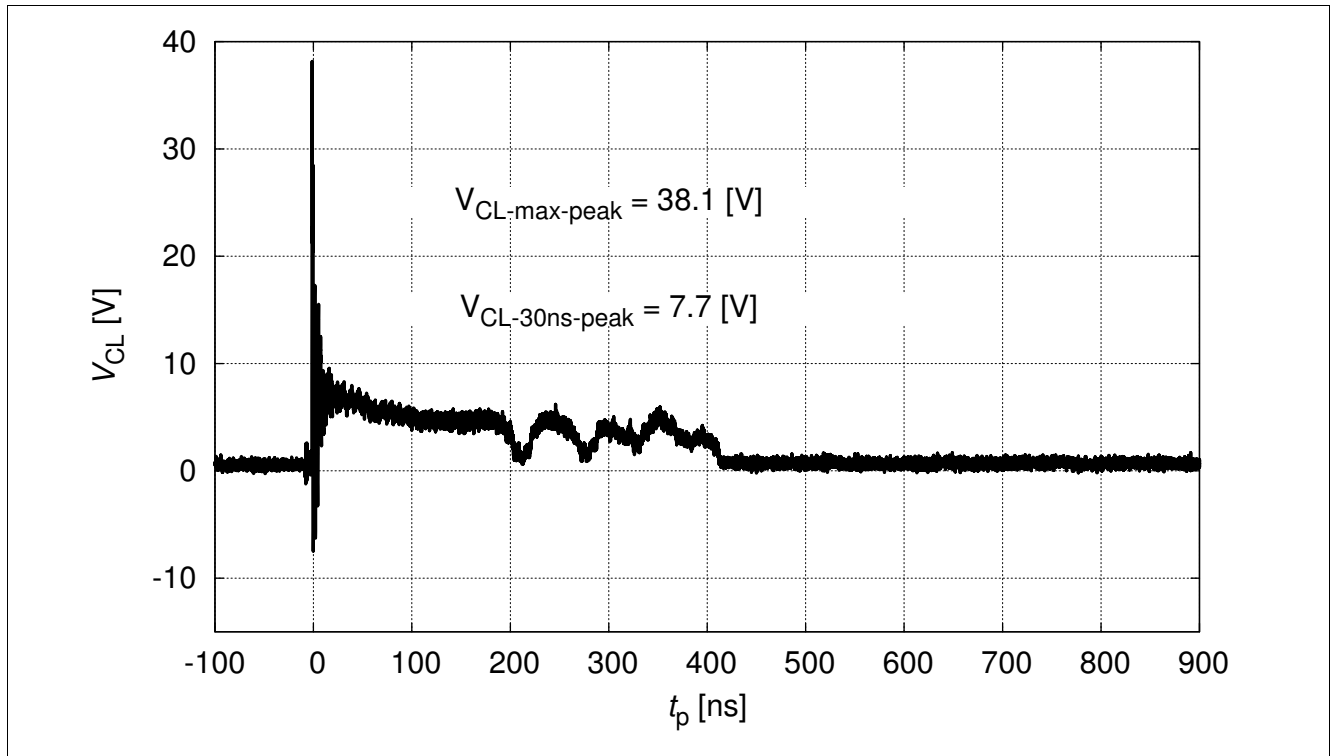


Figure 2-7 IEC61000-4-2 : $V_{CL} = f(t)$, 8 kV positive pulse from pin 1 to pin 2

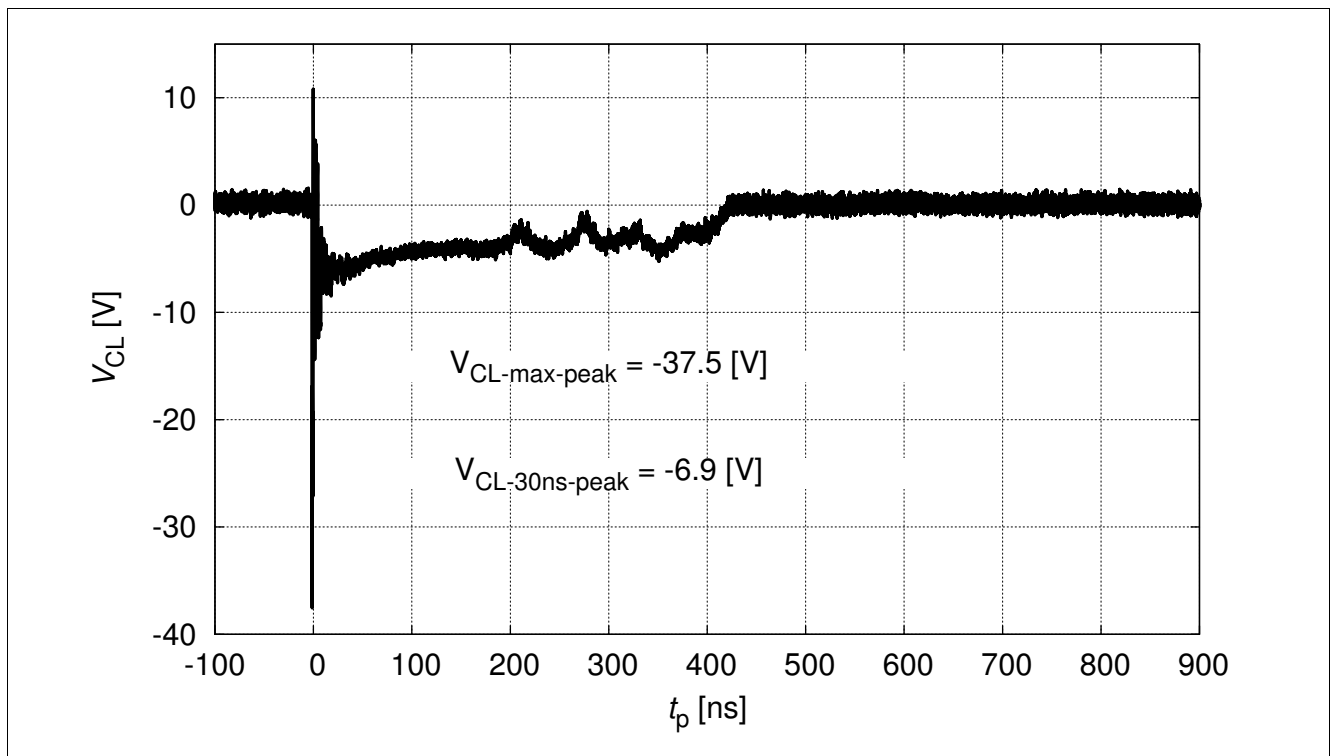


Figure 2-8 IEC61000-4-2 : $V_{CL} = f(t)$, 8 kV negative pulse from pin 1 to pin 2

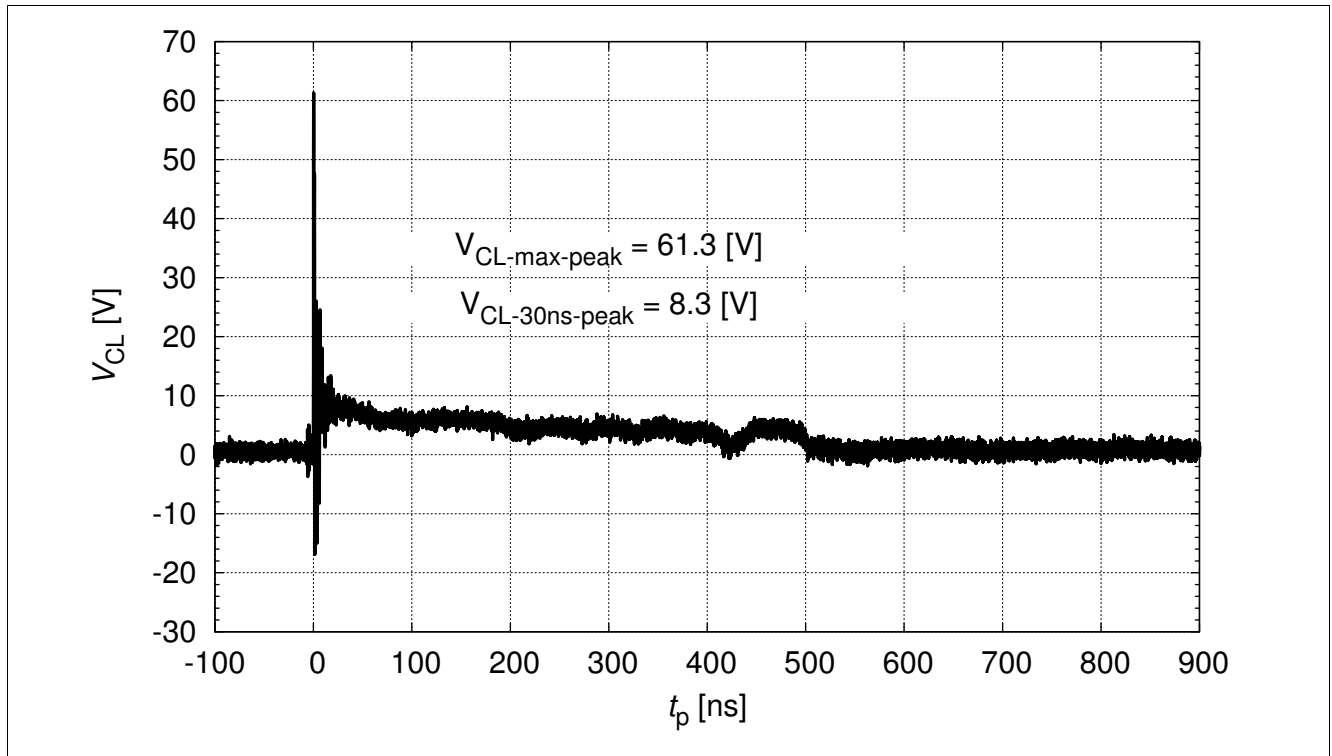


Figure 2-9 IEC61000-4-2 : $V_{CL} = f(t)$, 15 kV positive pulse from pin 1 to pin 2

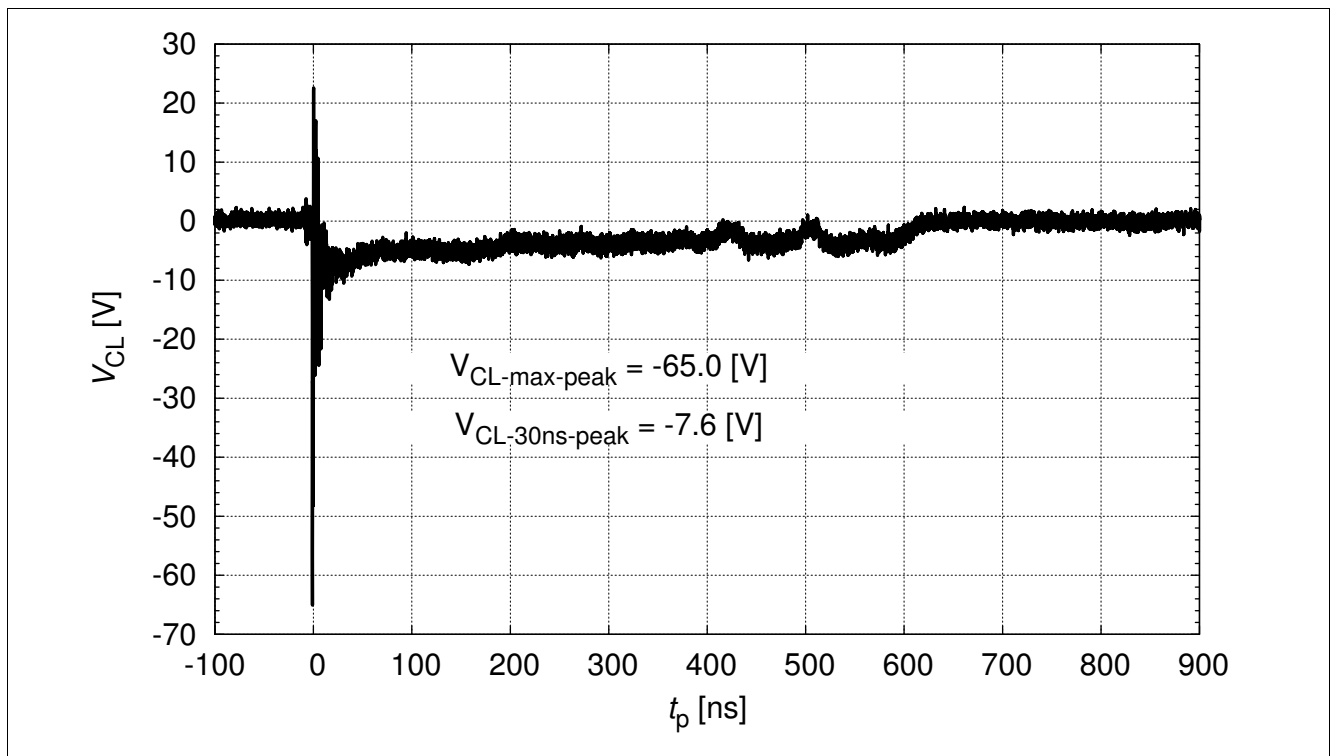


Figure 2-10 IEC61000-4-2 : $V_{CL} = f(t)$, 15 kV negative pulse from pin 1 to pin 2

3 Application Information

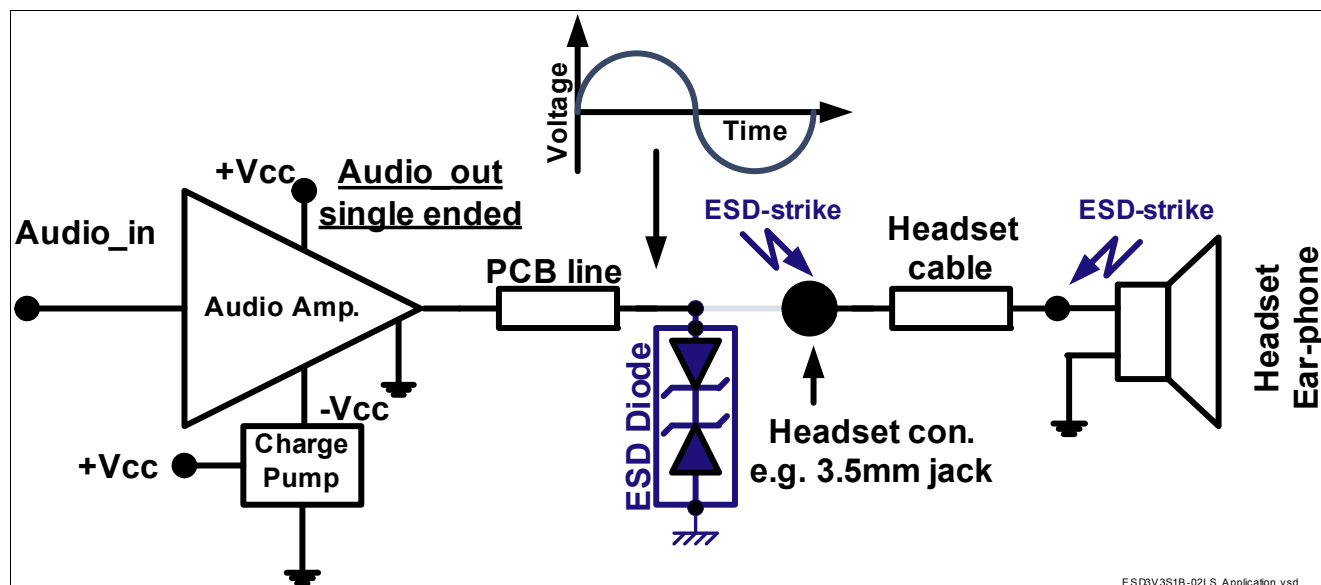


Figure 3-1 Single line, bi-directional ESD / Transient protection

4 Package Information

4.1 TSSLP-2-3

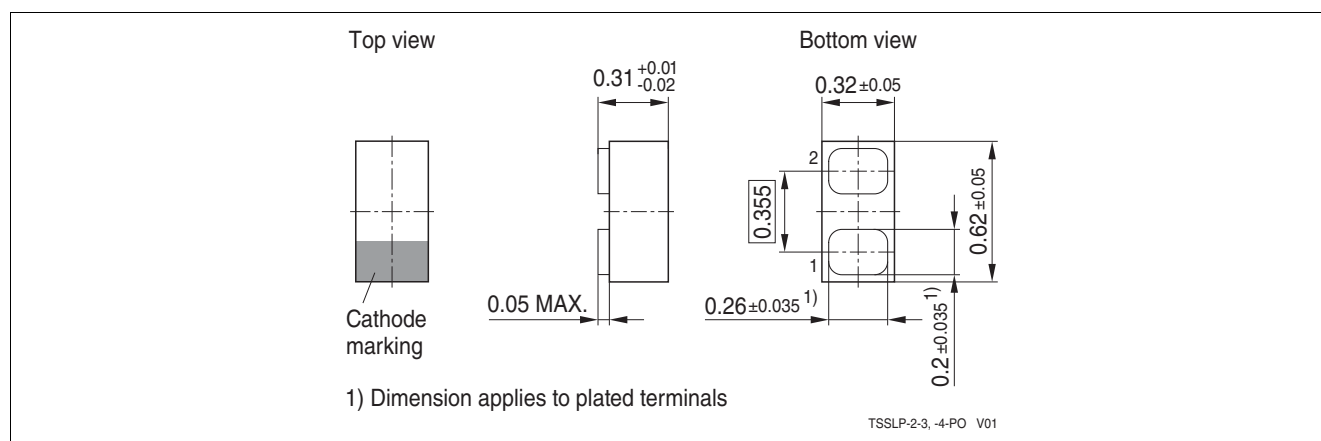


Figure 4-1 TSSLP-2-3: Package overview (dimension in mm)

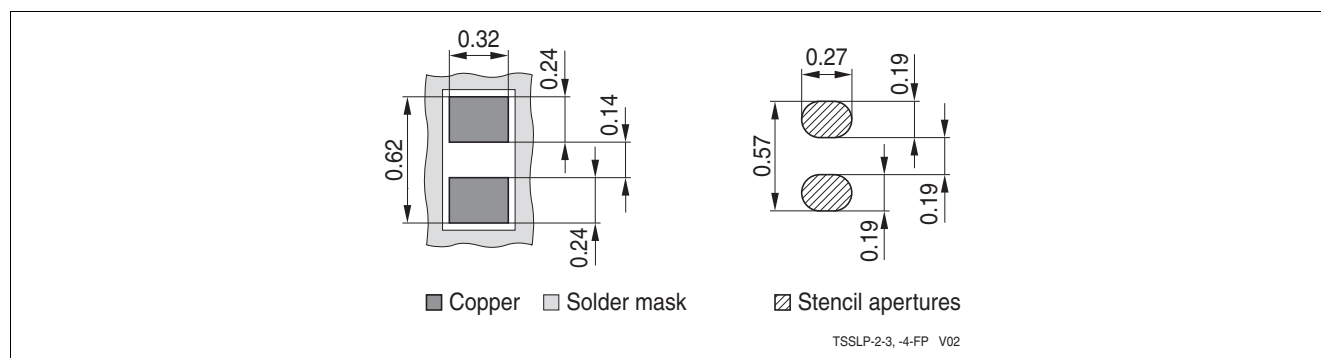


Figure 4-2 TSSLP-2-3: Footprint (dimension in mm)

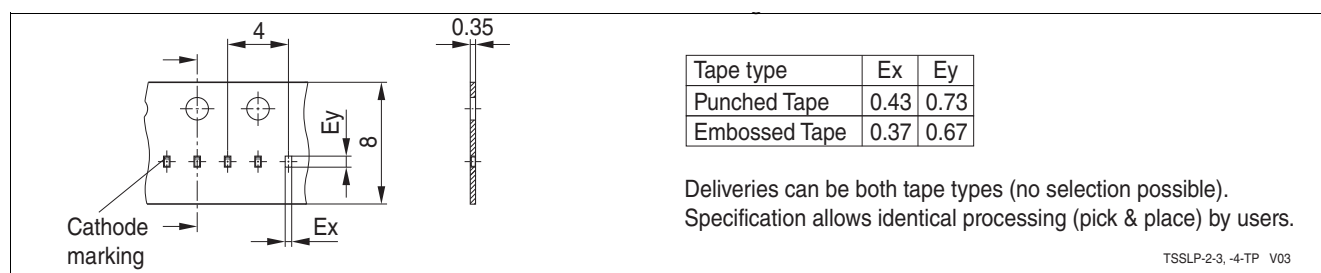


Figure 4-3 TSSLP-2-3: Tape information (dimension in mm)

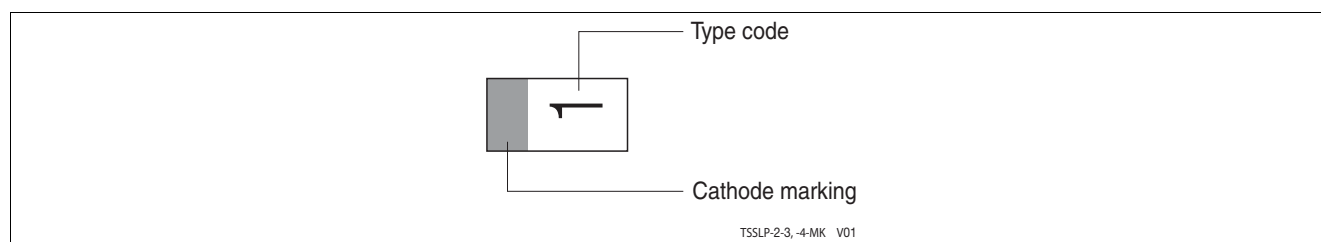


Figure 4-4 TSSLP-2-3: Marking (example)

4.2 TSLP-2-19

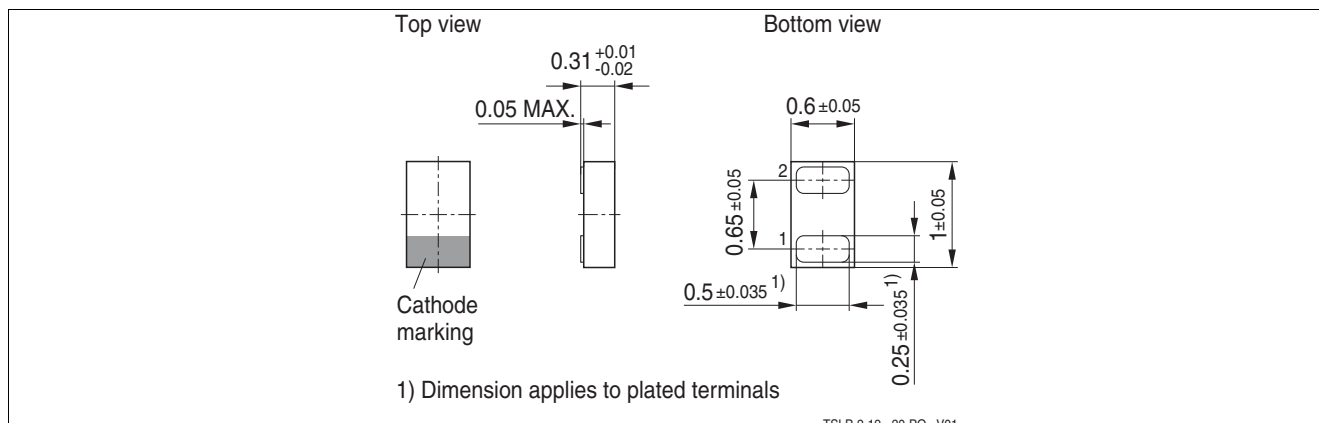


Figure 4-5 TSLP-2-19: Package outline(dimension in mm), proposal

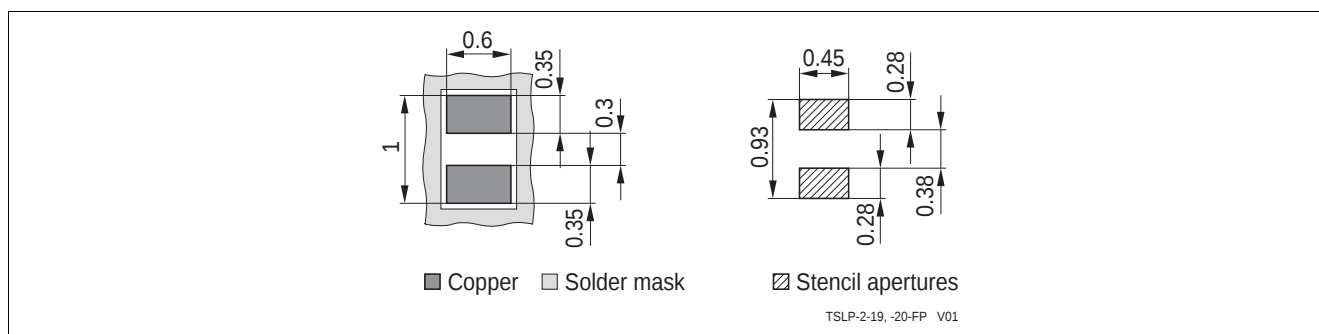


Figure 4-6 TSLP-2-19: Footprint (dimension in mm), proposal

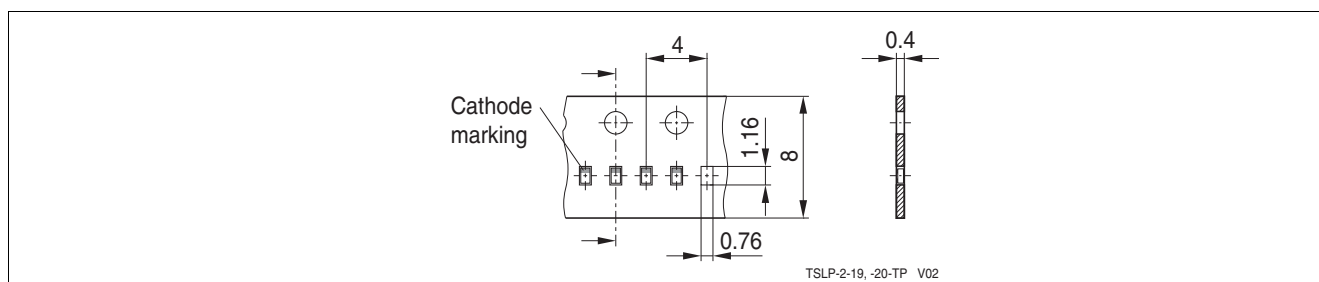


Figure 4-7 TSLP-2-19: Tape information (dimension in mm), proposal

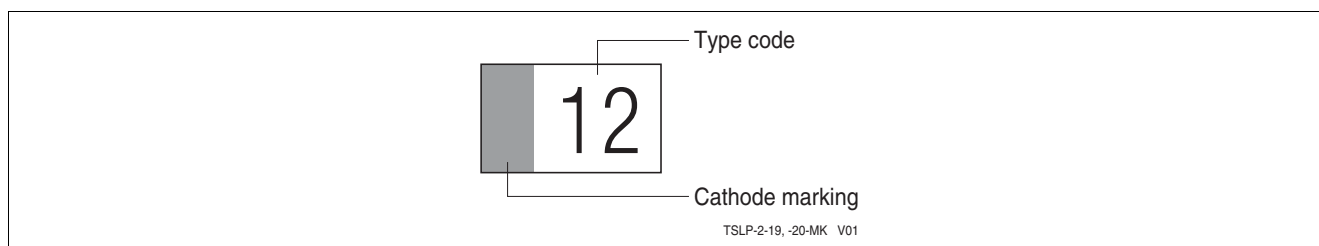


Figure 4-8 TSLP-2-19: Marking (example)

References

- [1] Infineon AG - **Application Note AN210:** Effective ESD Protection design at System Level Using VF-TLP Characterization Methodology
- [2] Infineon AG - Recommendations for PCB Assembly of Infineon TSLP and TSSLP Packages

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